

Oxygenates production in a microfluidic dielectric barrier discharge device sustained in Ar/CH₄/O₂

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ABSTRACT

Reforming of methane (CH₄) is a process to produce syngas (CO/H₂) and other value-added chemicals including oxygenates such as methanol (CH₃OH). Atmospheric pressure plasmas have the potential to be more energy efficient than traditional reforming methods as value-added chemicals can be synthesized directly in the plasma without requiring an additional step. In this paper, we discuss the results from a computational investigation of the formation of oxygenates by CH₄ oxidation in the presence of Ar, including CH₃OH and CH₂O, in a nanosecond pulsed dielectric barrier discharge. The plasma is formed in a microfluidic channel whose small dimensions are ideal for plasma formation at atmospheric pressure. The production and consumption mechanisms of dominant radicals and long-lived species are discussed in detail for the base case conditions of Ar/CH₄/O₂ = 50/25/25. CH₃OH is produced primarily by CH₃O reacting with CH₃O and CH₃O₂ reacting with OH, while CH₂O formation relies on reactions involving CH₃O and CH₃. The most abundant oxygenate formed is CO (produced by H abstraction from CHO). However, the greenhouse gas CO₂ is also formed as a by-product. The effects of gas mixture are examined to maximize the CH₃OH and CH₂O densities while decreasing the CO₂ density. Increasing the Ar percentage from 0% to 95% decreased the CH₃OH and CH₂O densities. At low Ar percentages, this is due to an increase in consumption of CH₃OH and CH₂O, while at high Ar percentages (>40% Ar), the production of CH₃OH and CH₂O is decreased. However, both CO and CO₂ reached peak densities at 70%–90% Ar. Changing the CH₄/O₂ ratio while keeping 50% Ar in the discharge led to increased CH₃OH and CH₂O production, reaching peak densities at 35%–40% CH₄. The CO and CO₂ densities decreased beyond 20% CH₄, indicating that a CH₄ rich discharge is ideal for forming the desired oxygenates.

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I. INTRODUCTION

Reforming of methane (CH₄) is a chemical process used widely to produce syngas, a mixture of carbon monoxide (CO) and hydrogen (H₂). CH₄ reforming can be performed through two processes—steam reforming in the presence of H₂O and dry reforming in the presence of CO₂.¹ While steam reforming of CH₄ is commonly used in industrial processes, it is an endothermic process requiring

elevated pressures and temperatures.¹ The syngas produced in steam reforming of CH₄ is often further converted to other value-added compounds. One of the most common value-added compounds produced is methanol (CH₃OH).² From CH₃OH, formaldehyde (CH₂O) is produced by oxidation.

Atmospheric pressure plasmas, when sustained in CH₄, convert CH₄ to other compounds.^{3–7} Previous research has examined dry reforming of CH₄ in plasmas, where CH₄ and CO₂ are

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converted to syngas and other compounds.^{8–15} Plasmas have the potential to be more energy efficient than other CH₄ reforming processes as plasmas can be sustained near ambient temperature and at atmospheric pressure. Hot (several eV) electrons dissociate and ionize the neutral feedstock gases, leading to complex plasma chemistry while retaining low gas temperatures. CH₄ conversion proceeds through direct electron-impact dissociation of CH₄ or reactions of other plasma-produced radicals and excited states with CH₄, while the low gas temperature enables selectivity.

Conversion of CH₄ in the presence of a noble gas has been previously investigated.^{16–19} Janeco *et al.* examined electron kinetics in He/CH₄/CO₂ mixtures and showed that addition of He shifted the electron energy distribution to higher energies.²⁰ The higher energy electrons led to increased conversion of CH₄ and CO₂. Rahmani and Nikravech showed that addition of Ar increased the electron density and electron temperature in CH₄/CO₂ mixtures.²¹ Jo *et al.* showed that the identity of the noble gas (He, Ne, Ar, Kr, or Xe) affected the electron temperature and density.²² Ozkan *et al.* examined the difference in CH₄ and CO₂ conversion in the presence of either Ar or He.¹² They showed that the conversion of CH₄ was higher for He than for Ar, while the conversion of CO₂ was higher for Ar than He.

Studies have also focused on the production of oxygenates, including CH₃OH and CH₂O.²³ De Bie *et al.* modeled the production of oxygenates in CH₄/O₂ mixtures and CH₄/CO₂ mixtures in a nanosecond pulsed dielectric barrier discharge (DBD).²⁴ They predicted the formation of many oxygenated species, including CH₃OH, CH₃OOH, CH₂O, C₂H₅OOH, C₂H₅OH, and CH₃CHO. Biswas *et al.* examined the production of oxygenates from CO₂ and C₂H₆.²⁵ The dominant product was CO, and other hydrocarbons and oxygenated species were also formed. Kolb *et al.* investigated the production of oxygenates in a DBD with 97% He.²⁶ The addition of O₂ to He/CH₄/CO₂ was shown to increase CH₃OH and CH₂O yields. Li *et al.* examined oxygenate production from CH₄/CO₂/O₂ discharges.²⁷ The increased amounts of O, OH, and HO₂ were responsible for enhancing the oxygenate production with O₂ addition. Oxygenate production in plasma-catalytic systems has also been studied.^{28–30}

As we advance our knowledge of oxygenate production from CH₄ plasmas, the manner of implementing those processes also becomes important. That implementation should consider the method of excitation (e.g., DBD, microwave, glow, pulsing) and throughput. For example, pulsed ns DBDs have some advantages over microwave excitation when maintaining low gas temperatures, which is an important consideration in the conversion process. Micro-plasmas have the advantage of rapidly rising voltage pulses, well-controlled power deposition, and temperature control. DBD plasmas sustained in micro-channels (as found in microfluidic devices) enable such control as well as management of products through, for example, solvation into solution. Large throughput is achieved by parallel processing.

In this study, we used the 0-dimensional (0D) model *GlobalKin* to assess the production of CH₃OH and CH₂O in a pulsed nanosecond DBD sustained in Ar/CH₄/O₂ flowing through a microfluidic channel, ideal for producing uniform flows with high power deposition at atmospheric pressure. The goal is to examine mechanisms for CH₃OH and CH₂O production while minimizing the production of the greenhouse gas CO₂. The

dominant production and consumption mechanisms of the plasma-produced radicals and long-lived species are identified. Common oxygenates formed include CH₃OH, CH₂O, and CO. The plasma-produced species that do not contain oxygen include H₂, C₂H₄, and C₂H₆. After examining the base case, the consequences of the gas mixture are examined. When increasing the Ar content while keeping CH₄/O₂ = 1/1, CH₃OH and CH₂O densities decrease while the density of CO₂ increases to 90% Ar. A mixture of 50% Ar and 35%–40% CH₄ (10%–15% O₂) maximizes CH₃OH and CH₂O production while also minimizing the amount of CO₂ formed.

The model is described in Sec. II. The results of the base case are discussed in Sec. III, including delineation of the production and consumption mechanisms of abundant radicals and long-lived species. Consequences of the gas mixture are discussed in Sec. IV, and conversion and energy expenditures are discussed in Sec. V. Concluding remarks are presented in Sec. VI.

II. DESCRIPTION OF MODEL

GlobalKin is a 0D plasma chemistry model that integrates continuity equations for neutral and charged species.³¹ Sources and losses for these species include chemical reactions, flow, and diffusion to bounding surfaces of the plasma. Electron temperature T_e and gas temperature T_{gas} are calculated using their respective energy equations. A stationary solution of Boltzmann's equation produced using a two-term spherical harmonic expansion is used to compute the electron energy distribution at different values of E/N (electric field/gas number density). The resulting values of electron temperature T_e are then the basis of creating a look-up table of electron-impact rate coefficients and transport coefficients as a function of T_e . The look-up table is updated at the beginning of each discharge pulse by recomputing the electron energy distributions to reflect the changes in the gas mole fractions.

The gas mixture examined is Ar/CH₄/O₂, and the base case conditions are Ar/CH₄/O₂ = 50/25/25. The reaction mechanism includes 122 species, listed in Table I, and 3265 reactions between those species. The Ar/O₂/H₂O mechanism is based on Van Gaens and Bogaerts,³² and the Ar/CH₄/H₂O mechanism is based on our previous work.³³ Additional reactions between hydrocarbon species and oxygen species were added to the mechanism and are listed in the supplementary material. Important reactions in the production and consumption of radicals and long-lived species are listed in Tables II and III, respectively. These reactions will be discussed in the following section.

The geometry in this work replicates that of our previous study of methyl radical production in a microfluidic channel.³³ The microfluidic channel serves as a dielectric barrier discharge (DBD). The channel dimensions are 500 × 500 μm². The power is pulsed on ns timescales, ramping up over 15 ns, staying constant for 30–45 ns, and decreasing to 0 W at 60 ns. The peak power deposition is 228 kW cm⁻³, and the energy deposited into the plasma is 10 mJ cm⁻³ per pulse. The pulse repetition rate is 10 kHz (0.1 ms period), and the evolution over 20 pulses (2 ms) was tracked. The flow rate is 0.1 SCCM to approximate plug flow, and the outflow was adjusted to maintain 1 atm at a timescale of 0.1 ms.

Since *GlobalKin* is a 0D model, it does not account for spatial dynamics such as ionization waves in the bulk plasmas or along

TABLE I. Species included in the reaction mechanism.

e, Ar, Ar(1s ₁), Ar(1s ₂), Ar(1s ₃), Ar(1s ₄), Ar(4P), Ar(4D), Ar ⁺ , Ar ₂ ⁺ , Ar ₂ ⁺ , ArH ⁺
H, H [*] , H ⁺ , H ⁻ , H ₂ , H ₂ (r), H ₂ (v), H ₂ [*] , H ₂ ⁺ , H ₃ ⁺
H ₂ O, H ₂ O(v), H ₂ O ⁺ , H ₃ O ⁺ , OH, OH [*] , OH ⁺ , OH ⁻ , HO ₂ , H ₂ O ₂ , H ₂ O ⁺ (H ₂ O), O ₂ ⁺ (H ₂ O), H ₃ O ⁺ (H ₂ O), O ₂ ⁻ (H ₂ O), O ₂ ⁻ (H ₂ O) ₂ , O ⁻ (H ₂ O), OH ⁻ (H ₂ O), OH ⁻ (H ₂ O) ₂
O ₂ , O ₂ (v), O ₂ (r), O ₂ (¹ Δ), O ₂ (¹ Σ), O ₂ ⁺ , O ₂ ⁻ , O ₄ ⁺ , O, O(¹ D), O ⁺ , O ⁻ , O ₃ , O ₃ [*] , O ₃ ⁻
CH ₄ , CH ₄ (v), CH ₄ ⁺ , CH ₅ ⁺ , CH ₃ , CH ₃ (v), CH ₃ ⁺ , CH ₂ , CH ₂ (v), CH ₂ ⁺ , CH ₂ ⁻ , CH, CH ⁺ , C, C ⁺
C ₂ H ₆ , C ₂ H ₆ (v), C ₂ H ₆ ⁺ , C ₂ H ₅ , C ₂ H ₅ ⁺ , C ₂ H ₄ , C ₂ H ₄ ⁺ , C ₂ H ₃ , C ₂ H ₃ ⁺ , C ₂ H ₂ , C ₂ H ₂ ⁺ , C ₂ H ₂ ⁻ , C ₂ H, C ₂ H ⁺ , C ₂ , C ₂ ⁺
C ₃ H ₈ , C ₃ H ₇ -N (<i>n</i> -propyl radical), C ₃ H ₇ I (iso-propyl radical), C ₃ H ₆ , C ₃ H ₅ , C ₃ H ₄ , C ₃ H ₃ , C ₃ H ₂
CHO, CHO ⁺ , CH ₂ O, CH ₂ O ⁺ , CH ₃ O, CH ₃ O ⁺ , CH ₂ OH, CH ₂ OH ⁺ , CH ₃ OH, CH ₃ OH ⁺ , CH ₃ OH ₂ ⁺ , CH ₃ OOH, CH ₃ O ₂
CO, CO(v), CO ⁺ , CO ₂ , CO ₂ (v), CO ₂ ⁺
C ₂ H ₅ OH, C ₂ H ₅ O, C ₂ H ₅ OOH, C ₂ H ₅ O ₂ , CH ₃ CO, CH ₂ CO, CH ₃ CHO, CH ₂ CHO, C ₂ HO

surfaces. The computational expediency of global models is that they enable detailed analysis of the plasma chemistry and can be used to compute plasma chemical dynamics over multiple pulses and long time scales. We acknowledge that chemical conversion processes that depend on the specifics of these spatial dynamics will not be captured in a global model. However, we expect that the trends predicted by global models will hold for higher dimensional models and experiments.

III. OXYGENATED SPECIES PRODUCTION

In this section, the radical and long-lived species production and consumption for the base case of Ar/CH₄/O₂ = 50/25/25 are discussed. The plasma properties are discussed in Sec. III A. The production and consumption mechanisms of radicals and long-lived species are discussed in Secs. III B and III C, respectively.

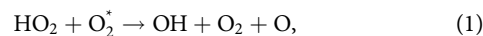
A. Plasma properties

The plasma properties are shown in Fig. 1 over the last of 20 pulses. The electrons are initially seeded with a density of 10⁹ cm⁻³ at the beginning of each discharge pulse. As power is applied with this initially small electron density, T_e increases to 4.9 eV, above the quasi-steady-state value, to sustain an electron avalanche. With the increase in electron density, T_e decreases. During the constant power portion of the pulse, the electron density and T_e reach their quasi-steady state values of 1.8 × 10¹³ cm⁻³ and 3.1 eV. As the power decreases at the end of the pulse, T_e rapidly decreases to lower the power dissipation per electron. Electrons rapidly recombine with positive ions, dominantly dissociative recombination, or attach to form negative ions including OH⁻, O₂⁻, and O⁻. The gas temperature increases from its initial value of 300 K up to 403 K at 2 ms.

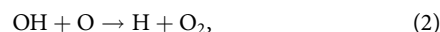
B. Radical production and consumption

The dominant radicals formed in the Ar/CH₄/O₂ system are shown in Fig. 2, and the production and consumption reactions of each radical are detailed in Table II for those processes that contribute more than 5% of the total production or consumption of the radical. The most important reactions will be discussed in this section.

The reactive oxygen species (ROS) radicals are shown in Fig. 2(a). Since there is a large fraction of O₂ in the gas, O is the most abundant ROS radical formed. O is formed through electron-impact of O₂ (61% of O production over the 20 pulses) as well as through



thereby producing 25% of the O produced over the 20 pulses. O is consumed through three-body formation of O₃ (40%) and formation of O₂ with other radicals including CH₃O₂, HO₂, OH, and CH₃O. H is also produced, primarily from the electron-impact of CH₄ (34%) and



thereby contributing 28% of H production over 20 pulses. H is consumed by three-body recombination with O₂ forming HO₂ (67%). While O and H are formed from direct electron-impact reactions with the feedstock gases O₂ and CH₄, HO₂, and OH rely on those radicals to be generated first. As a result, HO₂ and OH reach their maximum densities after the discharge pulse, while the densities of O and H peak as the pulse ends. HO₂ is dominantly produced by three-body recombination of H and O₂ (42%), though 30% of HO₂ is produced by



HO₂ remains at an elevated density between the pulses, reaching 6.7 × 10¹⁴ cm⁻³ before the final pulse. HO₂ is consumed in reactions with O₂(¹Δ) (56%) and O (32%). Both O₂(¹Δ) and O are produced during the pulse and consumed in the afterglow, decreasing the amount of HO₂ consumed in the afterglow. OH relies on HO₂ to be produced, both through reactions with O₂(¹Δ) (45%) and formation of O₂ from HO₂ (26%). OH is consumed in H abstraction from CH₄ (25%) and CH₂O (20%).

The dominant hydrocarbon radicals are shown in Fig. 2(b) over the last of 20 pulses. CH₃ is the most abundant hydrocarbon radical, produced by H abstraction from CH₄ by OH (39%), electron-impact dissociation of CH₄ (26%), and O reacting with CH₃O (18%). CH₃ is primarily consumed in association with O₂ to form CH₃O₂ (87%), operating in the high-pressure limit. The next most abundant hydrocarbon radical is CH₂, a lumped state of the triplet and singlet states. CH₂ is formed by the electron-impact dissociation of CH₄ (60%) as well as dissociative excitation transfer (DET) from the Ar(4s) multiplet (Ar(1s₁), Ar(1s₂), Ar(1s₃), Ar(1s₄)) to CH₄ (26%). Higher energy Ar states including Ar(4P) and Ar(4D) directly ionize CH₄ instead of dissociating CH₄. DET also contributes to CH₃ production. The integrated rate of DET to form CH₂ is double that of CH₃, but the contribution of DET to CH₃ formation is low (1%) as there are other pathways to form CH₃.

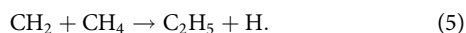
TABLE II. Dominant production and consumption mechanisms of radicals produced in Ar/CH₄/O₂ = 50/25/25. Production and consumption reactions are listed if they contribute more than 5% of the total production and consumption over 20 pulses.

Production reactions	Integrated contribution to production over 20 pulses (cm ⁻³)	Consumption reactions	Integrated contribution to consumption over 20 pulses (cm ⁻³)
O			
e + O ₂ → O + O + e	1.8 × 10 ¹⁷ (61%)	O + O ₂ + M → O ₃ /O ₃ * + M, M = CH ₄ , Ar, O ₂ , O ₃ , H ₂ O	1.2 × 10 ¹⁷ (40%)
HO ₂ + O ₂ ^(1Δ) → OH + O ₂ + O	7.2 × 10 ¹⁶ (25%)	CH ₃ O ₂ + O → CH ₃ O + O ₂ HO ₂ + O → OH + O ₂ OH + O → H + O ₂ CH ₃ O + O → CH ₃ + O ₂	5.5 × 10 ¹⁶ (19%) 4.1 × 10 ¹⁶ (14%) 2.2 × 10 ¹⁶ (7.5%) 1.9 × 10 ¹⁶ (6.5%)
H			
e + CH ₄ → CH ₃ + H + e	2.7 × 10 ¹⁶ (34%)	H + O ₂ + M → HO ₂ + M, M = CH ₄ , Ar, O ₂ , O ₃ , H ₂ O	5.4 × 10 ¹⁶ (67%)
OH + O → H + O ₂	2.2 × 10 ¹⁶ (28%)	H + O ₃ → OH + O ₂	1.8 × 10 ¹⁶ (22%)
CH ₃ + O → CH ₂ O + H	6.4 × 10 ¹⁵ (8.0%)		
CH ₃ OH + OH → CH ₂ O + H ₂ O + H	4.7 × 10 ¹⁵ (5.8%)		
HO₂			
H + O ₂ + M → HO ₂ + M, M = CH ₄ , Ar, O ₂ , O ₃ , H ₂ O	5.4 × 10 ¹⁶ (42%)	HO ₂ + O ₂ ^(1Δ) → OH + O ₂ + O	7.2 × 10 ¹⁶ (56%)
CHO + O ₂ → CO + HO ₂	3.9 × 10 ¹⁶ (30%)	HO ₂ + O → OH + O ₂	4.2 × 10 ¹⁶ (32%)
CH ₃ O ₂ + OH → CH ₃ O + HO ₂	1.5 × 10 ¹⁶ (12%)		
CH ₃ O + O ₂ → CH ₂ O + HO ₂	8.6 × 10 ¹⁵ (6.6%)		
OH			
HO ₂ + O ₂ ^(1Δ) → OH + O ₂ + O	7.2 × 10 ¹⁶ (45%)	CH ₄ + OH → CH ₃ + H ₂ O	4.0 × 10 ¹⁶ (25%)
HO ₂ + O → OH + O ₂	4.1 × 10 ¹⁶ (26%)	CH ₂ O + OH → CHO + H ₂ O	3.2 × 10 ¹⁶ (20%)
H + O ₃ → OH + O ₂	1.8 × 10 ¹⁶ (11%)	OH + O → H + O ₂ CH ₃ O ₂ + OH → CH ₃ O + HO ₂ CH ₃ O ₂ + OH → CH ₃ OH + O ₂	2.2 × 10 ¹⁶ (14%) 1.5 × 10 ¹⁶ (9.5%) 1.5 × 10 ¹⁶ (9.5%)
CH₃			
CH ₄ + OH → CH ₃ + H ₂ O	4.0 × 10 ¹⁶ (39%)	CH ₃ + O ₂ → CH ₃ O ₂	9.1 × 10 ¹⁶ (87%)
e + CH ₄ → CH ₃ + H + e	2.8 × 10 ¹⁶ (26%)	CH ₃ + O → CH ₂ O + H	6.4 × 10 ¹⁵ (6.2%)
CH ₃ O + O → CH ₃ + O ₂	1.9 × 10 ¹⁶ (18%)		
CH ₂ + CH ₄ → CH ₃ + CH ₃	7.0 × 10 ¹⁵ (6.7%)		
CH₂			
e + CH ₄ → CH ₂ + H ₂ + e	4.6 × 10 ¹⁵ (60%)	CH ₂ + CH ₄ → C ₂ H ₅ + H	3.5 × 10 ¹⁵ (46%)
Ar* + CH ₄ → CH ₂ + H + H + Ar, Ar* = Ar(1s ₁), Ar(1s ₂), Ar(1s ₃), Ar(1s ₄)	2.0 × 10 ¹⁵ (26%)	CH ₂ + CH ₄ → CH ₃ + CH ₃	3.5 × 10 ¹⁵ (46%)
CH + CH ₄ → CH ₂ + CH ₃	7.8 × 10 ¹⁴ (10%)		
CH			
e + CH ₄ → CH + H ₂ + H + e	2.3 × 10 ¹⁵ (99%)	CH + CH ₄ → CH ₃ + CH ₂ CH + CH ₄ → C ₂ H ₄ + H CH + O ₂ → CO + O + H CH + O ₂ → CO ₂ + H CH + O ₂ → CHO + O CH + O ₂ → CO + OH	7.7 × 10 ¹⁴ (33%) 7.7 × 10 ¹⁴ (33%) 2.3 × 10 ¹⁴ (10%) 2.3 × 10 ¹⁴ (10%) 1.5 × 10 ¹⁴ (7%) 1.5 × 10 ¹⁴ (7%)
C₂H₅			
CH ₂ + CH ₄ → C ₂ H ₅ + H	3.5 × 10 ¹⁵ (98%)	C ₂ H ₅ + O ₂ → C ₂ H ₅ O ₂	3.4 × 10 ¹⁵ (95%)

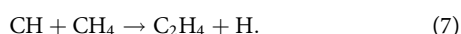
TABLE II. (Continued.)

Production reactions	Integrated contribution to production over 20 pulses (cm^{-3})	Consumption reactions	Integrated contribution to consumption over 20 pulses (cm^{-3})
CH₃O₂ CH ₃ + O ₂ → CH ₃ O ₂	9.1 × 10 ¹⁶ (99%)	CH ₃ O ₂ + O → CH ₃ O + O ₂ CH ₃ O ₂ + OH → CH ₃ O + HO ₂ CH ₃ O ₂ + OH → CH ₃ OH + O ₂	5.5 × 10 ¹⁶ (60%) 1.5 × 10 ¹⁶ (17%) 1.5 × 10 ¹⁶ (17%)
CH₃O CH ₃ O ₂ + O → CH ₃ O + O ₂ CH ₃ O ₂ + OH → CH ₃ O + HO ₂	5.5 × 10 ¹⁶ (72%) 1.5 × 10 ¹⁶ (20%)	CH ₃ O + CH ₃ O → CH ₂ O + CH ₃ OH CH ₃ O + O → CH ₃ + O ₂ CH ₃ O + O ₂ → CH ₂ O + HO ₂ CH ₃ O + O → CH ₂ O + OH CH ₃ O + OH → CH ₂ O + H ₂ O	3.6 × 10 ¹⁶ (47%) 1.9 × 10 ¹⁶ (25%) 8.6 × 10 ¹⁵ (11%) 7.6 × 10 ¹⁵ (9.9%) 4.2 × 10 ¹⁵ (5.5%)
CHO CH ₂ O + OH → CHO + H ₂ O CH ₂ O + O → CHO + OH	3.2 × 10 ¹⁶ (80%) 7.4 × 10 ¹⁵ (19%)	CHO + O ₂ → CO + HO ₂	3.9 × 10 ¹⁶ (98%)
C₂H₅O₂ C ₂ H ₅ + O ₂ → C ₂ H ₅ O ₂	3.4 × 10 ¹⁵ (97%)	C ₂ H ₅ O ₂ + OH → C ₂ H ₅ O + HO ₂ C ₂ H ₅ O ₂ + OH → C ₂ H ₅ OH + O ₂ C ₂ H ₅ O ₂ + HO ₂ → C ₂ H ₅ OOH + O ₂	2.3 × 10 ¹⁵ (67%) 7.7 × 10 ¹⁴ (22%) 3.5 × 10 ¹⁴ (10%)
C₂H₅O C ₂ H ₅ O ₂ + OH → C ₂ H ₅ O + HO ₂	2.3 × 10 ¹⁵ (99%)	C ₂ H ₅ O + O ₂ → CH ₃ CHO + HO ₂	2.2 × 10 ¹⁵ (95%)

CH₂ is consumed in reactions with CH₄, including



Each of these reactions has a rate coefficient of $1.4 \times 10^{-11} \exp(-250 \text{ K}/T_{\text{gas}}) \text{ cm}^3/\text{s}$ ³⁴ and contributes 46% to CH₂ consumption. The final CH_x radical formed is CH, dominantly generated through the electron-impact dissociation of CH₄ (99%). CH is consumed in a wide variety of reactions, including those with CH₄ by

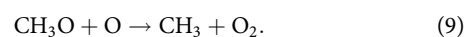
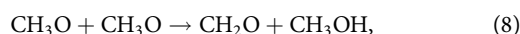


Both of these reactions consume 33% of CH. The most abundant C₂H_x radical is C₂H₅, requiring other radicals to be formed before it can be produced. C₂H₅ is formed from CH₂ associating with CH₄ (reaction 5, 98%). C₂H₅ is primarily consumed in forming the oxygenated radical C₂H₅O₂ by association with O₂ (95%).

The oxygenated radicals are shown in Fig. 2(c). Contrary to the ROS and hydrocarbon radicals, all oxygenated radicals rely on other radicals for their formation. Therefore, their densities all reach their maxima after the discharge pulse, following the production of their precursors during the discharge pulse. The most

abundant oxygenated radical is CH₃O₂, formed by the association of CH₃ and O₂ (99%). CH₃O₂ is primarily consumed in reactions with O (60%) and OH (34%), forming CH₃O and CH₃OH. Since CH₃O₂ is consumed in reactions with other radicals, CH₃O₂ persists between pulses with a density of $4.6 \times 10^{14} \text{ cm}^{-3}$ at the end of 20 pulses.

To examine the products CH₃O₂ formation on longer timescales than the 0.1 ms between pulses, 0.3 s of afterglow following the 20th pulse was simulated. During that additional 0.3 s afterglow, CH₃O₂ reacts with itself in two processes, forming CH₃OH, CH₂O, CH₃O, and O₂. CH₃O₂ also reacts with HO₂, forming CH₃OOH and O₂. Reactions of CH₃O₂ with O and OH are reduced in importance as O and OH concentrations decrease substantially after the plasma pulses. CH₃O is the next most abundant oxygenated radical, formed through the same reactions that consume CH₃O₂. CH₃O is consumed by



Reaction (8) consumes 47% of CH₃O, while reaction (9) consumes 25%. The final oxygenated radical with one C atom is CHO. CHO is formed by H abstraction from CH₂O by OH (80%) and O (19%). CHO is rapidly consumed in CO formation by H abstraction by O₂ (98%). Oxygenated radicals with two C atoms are also formed. Analogous to CH₃O₂, C₂H₅O₂ is formed through association reactions with C₂H₅ and O₂ (97%) and consumed in reactions

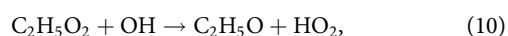
TABLE III. Dominant production and consumption mechanisms of long-lived species produced in Ar/CH₄/O₂ = 50/25/25. Production reactions are listed if they contribute more than 5% of the total production over 20 pulses. Consumption mechanisms are only listed if their integrated rates are more than 5% of the integrated production rate of the species.

Production reactions	Integrated contribution to production over 20 pulses (cm ⁻³)	Consumption reactions	Integrated contribution to consumption over 20 pulses (cm ⁻³)
H₂O			
CH ₄ + OH → CH ₃ + H ₂ O	4.0 × 10 ¹⁶ (40%)		
CH ₂ O + OH → CHO + H ₂ O	3.2 × 10 ¹⁶ (31%)		
O₃			
O + O ₂ + M → O ₃ + M, M = CH ₄ , Ar, O ₂ , O ₃ , H ₂ O	9.6 × 10 ¹⁶ (99.5%)	H + O ₃ → OH + O ₂	1.8 × 10 ¹⁶ (38%)
		O ₂ (¹ Σ) + O ₃ → O ₂ + O ₂ + O	1.3 × 10 ¹⁶ (28%)
H₂			
e + CH ₄ → CH ₂ + H ₂ + e	4.6 × 10 ¹⁵ (45%)		
e + CH ₄ → CH + H ₂ + H + e	2.3 × 10 ¹⁵ (23%)		
CH ₃ + O → CO + H ₂ + H	1.6 × 10 ¹⁵ (16%)		
CH ₃ ⁺ + CH ₄ → C ₂ H ₅ ⁺ + H ₂	5.6 × 10 ¹⁴ (5.6%)		
H₂O₂			
OH + OH + M → H ₂ O ₂ + M, M = CH ₄ , Ar, O ₂ , H ₂ O, O ₃	3.2 × 10 ¹⁵ (55%)	OH + H ₂ O ₂ → H ₂ O + HO ₂	1.0 × 10 ¹⁵ (94%)
HO ₂ + HO ₂ → H ₂ O ₂ + O ₂	2.5 × 10 ¹⁵ (41%)		
C₂H₄			
CH + CH ₄ → C ₂ H ₄ + H	7.7 × 10 ¹⁴ (65%)		
C ₂ H ₅ ⁺ + H ₂ O → H ₃ O ⁺ + C ₂ H ₄	3.5 × 10 ¹⁴ (30%)		
C₂H₆			
CH ₃ + CH ₃ → C ₂ H ₆	2.2 × 10 ¹⁴ (98%)	C ₂ H ₆ + OH → C ₂ H ₅ + H ₂ O	2.0 × 10 ¹³ (84%)
C₂H₂			
e + C ₂ H ₅ ⁺ → C ₂ H ₂ + H ₂ + H	1.5 × 10 ¹³ (27%)	C ₂ H ₂ + O → C ₂ HO + H	1.3 × 10 ¹³ (70%)
e + C ₂ H ₅ ⁺ → C ₂ H ₂ + H + H + H	8.4 × 10 ¹² (15%)	C ₂ H ₂ + O → CO + CH ₂	3.1 × 10 ¹² (18%)
C ₂ H ₄ ⁺ + O ₂ (H ₂ O) ₂ → C ₂ H ₂ + H + H + O ₂ + H ₂ O + H ₂ O	4.8 × 10 ¹² (8.7%)		
C ₂ H ₄ ⁺ + O ₃ ⁻ → C ₂ H ₂ + H + H + O ₃	3.6 × 10 ¹² (6.5%)		
C ₂ H ₃ + O ₂ → C ₂ H ₂ + HO ₂	3.3 × 10 ¹² (6.0%)		
C₃H₈			
C ₂ H ₅ + CH ₃ → C ₃ H ₈	6.3 × 10 ¹² (99.3%)		
C₃H₆			
C ₂ H ₄ + CH ₂ → C ₃ H ₆	2.0 × 10 ¹² (90%)	C ₃ H ₆ + O → CHO + C ₂ H ₅	1.1 × 10 ¹² (58%)
C ₂ H ₃ + CH ₃ → C ₃ H ₆	1.4 × 10 ¹¹ (6.5%)	C ₃ H ₆ + O → CH ₂ CO + CH ₃ + H	7.6 × 10 ¹¹ (41%)
CO			
CHO + O ₂ → CO + HO ₂	3.9 × 10 ¹⁶ (93%)		
CH₃OH			
CH ₃ O + CH ₃ O → CH ₂ O + CH ₃ OH	1.8 × 10 ¹⁶ (53%)	CH ₃ OH + OH → CH ₂ O + H ₂ O + H	4.7 × 10 ¹⁵ (45%)
CH ₃ O ₂ + OH → CH ₃ OH + O ₂	1.5 × 10 ¹⁶ (45%)	CH ₃ OH + OH → CH ₂ OH + H ₂ O	4.0 × 10 ¹⁵ (38%)
CH₂O			
CH ₃ O + CH ₃ O → CH ₂ O + CH ₃ OH	1.8 × 10 ¹⁶ (32%)	CH ₂ O + OH → CHO + H ₂ O	3.2 × 10 ¹⁶ (79%)
CH ₃ O + O ₂ → CH ₂ O + HO ₂	8.6 × 10 ¹⁵ (15%)	CH ₂ O + O → CHO + OH	7.4 × 10 ¹⁵ (18%)
CH ₃ O + O → CH ₂ O + OH	7.8 × 10 ¹⁵ (13%)		
CH ₃ + O → CH ₂ O + H	6.4 × 10 ¹⁵ (11%)		

TABLE III. (Continued.)

Production reactions	Integrated contribution to production over 20 pulses (cm^{-3})	Consumption reactions	Integrated contribution to consumption over 20 pulses (cm^{-3})
$\text{CH}_3\text{OH} + \text{OH} \rightarrow \text{CH}_2\text{O} + \text{H}_2\text{O} + \text{H}$	4.7×10^{15} (8.3%)		
$\text{CH}_2\text{OH} + \text{O}_2 \rightarrow \text{CH}_2\text{O} + \text{HO}_2$	4.7×10^{15} (8.3%)		
$\text{CH}_3\text{O} + \text{OH} \rightarrow \text{CH}_2\text{O} + \text{H}_2\text{O}$	4.2×10^{15} (7.5%)		
CO₂			
$\text{CH}_3\text{CO} + \text{O} \rightarrow \text{CO}_2 + \text{CH}_3$	9.4×10^{14} (33%)		
$\text{OH} + \text{CO} \rightarrow \text{CO}_2 + \text{H}$	6.8×10^{14} (24%)		
$\text{CH} + \text{O}_2 \rightarrow \text{CO}_2 + \text{H}$	2.3×10^{14} (8.1%)		
$\text{CHO} + \text{O} \rightarrow \text{CO}_2 + \text{H}$	2.1×10^{14} (7.4%)		
$\text{CH}_3\text{CO} + \text{HO}_2 \rightarrow \text{CH}_3 + \text{CO}_2 + \text{OH}$	2.0×10^{14} (7.1%)		
$\text{CH}_2 + \text{O}_2 \rightarrow \text{CO}_2 + \text{H}_2$	1.8×10^{14} (6.2%)		
CH₃OOH			
$\text{CH}_3\text{O}_2 + \text{HO}_2 \rightarrow \text{CH}_3\text{OOH} + \text{O}_2$	1.9×10^{15} (94%)	$\text{CH}_3\text{OOH} + \text{OH} \rightarrow \text{CH}_3\text{O}_2 + \text{H}_2\text{O}$	5.7×10^{14} (95%)
$\text{CH}_3\text{O}_2 + \text{CH}_3\text{O} \rightarrow \text{CH}_2\text{O} + \text{CH}_3\text{OOH}$	1.2×10^{14} (5.7%)		
C₂H₅OH			
$\text{C}_2\text{H}_5\text{O}_2 + \text{OH} \rightarrow \text{C}_2\text{H}_5\text{OH} + \text{O}_2$	7.7×10^{14} (96%)		
CH₃CHO			
$\text{C}_2\text{H}_5\text{O} + \text{O}_2 \rightarrow \text{CH}_3\text{CHO} + \text{HO}_2$	2.2×10^{15} (95%)	$\text{CH}_3\text{CHO} + \text{OH} \rightarrow \text{CH}_3\text{CO} + \text{H}_2\text{O}$	1.2×10^{15} (69%)
		$\text{CH}_3\text{CHO} + \text{O} \rightarrow \text{OH} + \text{CH}_3\text{CO}$	4.6×10^{14} (26%)
C₂H₅OOH			
$\text{C}_2\text{H}_5\text{O}_2 + \text{HO}_2 \rightarrow \text{C}_2\text{H}_5\text{OOH} + \text{O}_2$	3.5×10^{14} (91%)	$\text{C}_2\text{H}_5\text{OOH} + \text{OH} \rightarrow \text{C}_2\text{H}_5\text{O}_2 + \text{H}_2\text{O}$	6.8×10^{13} (58%)
$\text{C}_2\text{H}_5\text{O}_2 + \text{C}_2\text{H}_5\text{O} \rightarrow \text{C}_2\text{H}_5\text{OOH} + \text{CH}_3\text{CHO}$	3.3×10^{13} (8.6%)	$\text{C}_2\text{H}_5\text{OOH} + \text{O} \rightarrow \text{C}_2\text{H}_5\text{O}_2 + \text{OH}$	4.9×10^{13} (41%)

with OH



Reaction (10) contributes 69% to $\text{C}_2\text{H}_5\text{O}_2$ consumption and reaction (11) contributes 17%. $\text{C}_2\text{H}_5\text{O}$ is formed by the reactions of $\text{C}_2\text{H}_5\text{O}_2$ and OH (99%), analogous to CH_3O . $\text{C}_2\text{H}_5\text{O}$ is consumed by

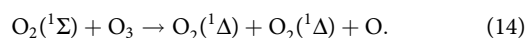
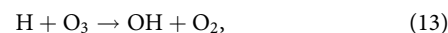


contributing 95% of $\text{C}_2\text{H}_5\text{O}_2$ consumption.

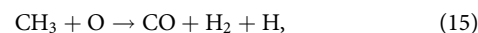
C. Long-lived species

The long-lived species that are formed by repetitive pulsing are shown in Fig. 3, and the dominant production and consumption reactions of each long-lived species are listed in Table III. Consumption reactions appear in Table III if they represent more than 5% of the total integrated production rate of that long-lived species.

The long-lived species that do not contain carbon are shown in Fig. 3(a). The most abundant of these is H_2O , reaching $8.6 \times 10^{16} \text{ cm}^{-3}$ (0.5% of the total density) at the end of 20 pulses. H_2O is formed by H abstraction by OH from CH_4 (40%) and CH_2O (31%). O_3 is also abundant in the discharge. O_3 is formed through three-body recombination of O and O_2 (99.5%). O_3 is consumed through



Reaction (13) contributes 38% to O_3 consumption, while reaction (14) contributes 28%. H_2 is formed through the electron-impact of CH_4 to form CH_2 (45%) and CH (23%). H_2 is also formed through



contributing 16% to H_2 production. The final long-lived species shown in Fig. 3(a) is H_2O_2 , formed by the three-body

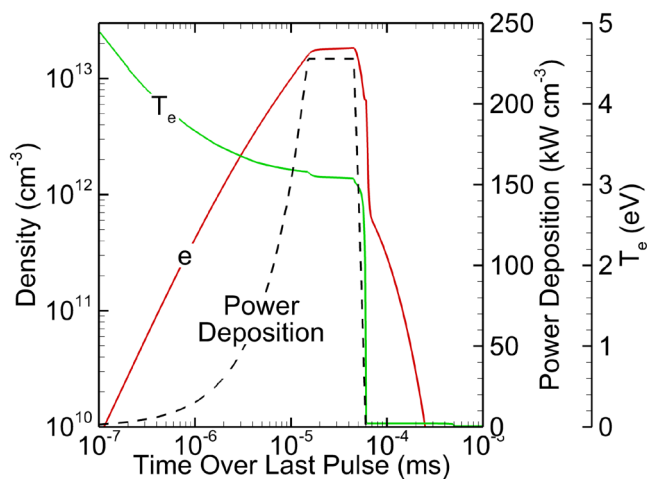
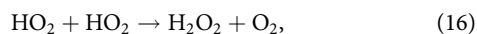
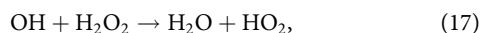


FIG. 1. Electron density and T_e of the Ar/CH₄/O₂ = 50/25/25 discharge over the last of 20 pulses. Power deposition is shown for reference.

recombination of OH (55% contribution) as well as



contributing 41% to H₂O₂ production. While OH forms H₂O₂, OH can also consume H₂O₂ through



contributing 94% to H₂O₂ consumption.

The long-lived hydrocarbons formed in the plasma are shown in Fig. 3(b). The most abundant long-lived hydrocarbon is C₂H₄ (ethylene). C₂H₄ is produced by CH reacting with CH₄ (65%) and charge-exchange between C₂H₅⁺ and H₂O (30%). The next most abundant long-lived hydrocarbon is C₂H₆ (ethane), formed dominantly from mutual reactions of CH₃ (98%). While mutual reactions of CH₃ are the dominant production mechanism of C₂H₆, this process only consumes 0.4% of CH₃ in the plasma. Instead of forming C₂H₆ as would be the dominant loss mechanism for CH₃ in an Ar/CH₄ plasma, CH₃ is converted into oxygenated species. C₂H₆ is consumed at an order of magnitude lower rate than the integrated rate by H abstraction with OH to form H₂O. The final C₂H_x species formed in abundance is C₂H₂ (acetylene), produced in multiple electron-ion recombination reactions with C₂H₅⁺ (42% total). While the C₂H_x species are the most abundant long-lived hydrocarbons, C₃H_x species are also formed. C₃H₈ (propane) is formed by the association of CH₃ and C₂H₅ (99.3%). C₃H₆ (propene) is formed by the association of CH₂ and C₂H₄ (90%) and is consumed in reactions with O by

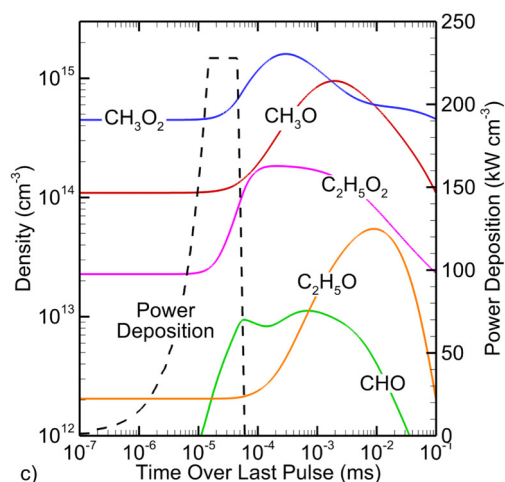
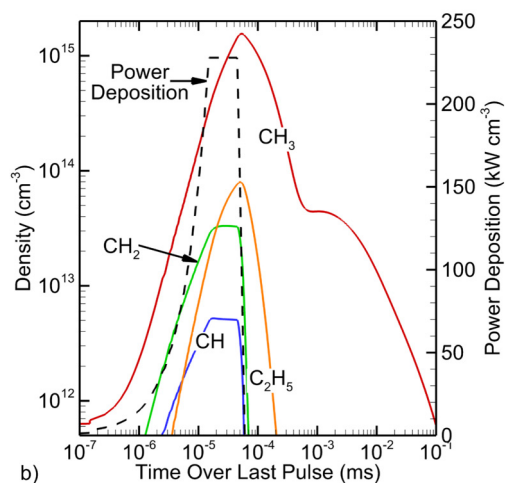
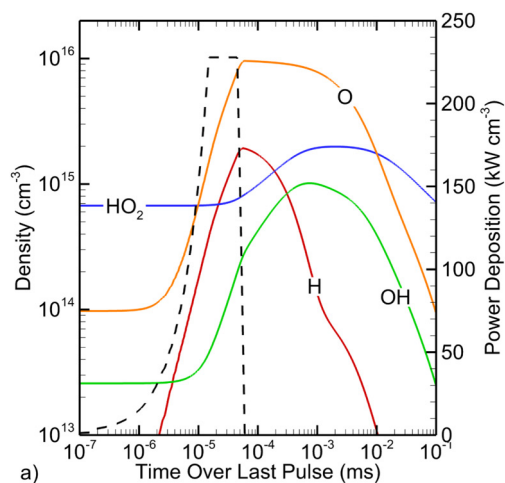


FIG. 2. Radicals generated in the Ar/CH₄/O₂ = 50/25/25 discharge over the last of 20 pulses. (a) Reactive oxygen species (ROS) radicals, (b) hydrocarbon radicals, and (c) oxygenated radicals.

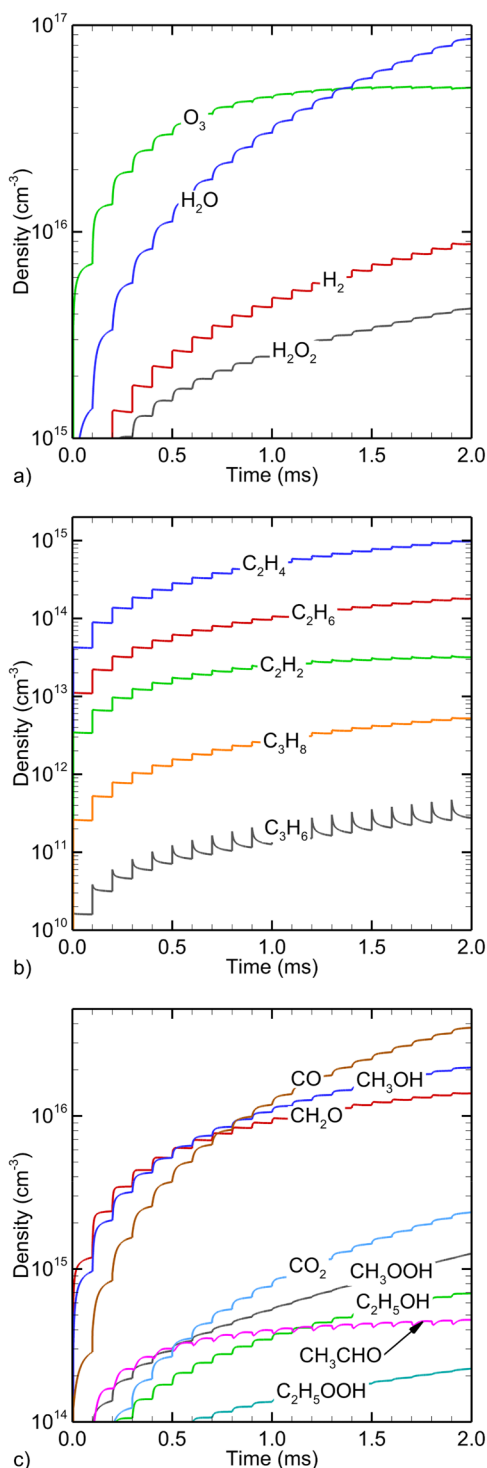
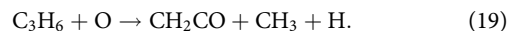


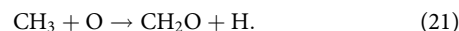
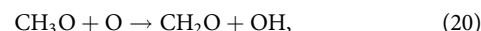
FIG. 3. Long-lived species generated in the Ar/CH₄/O₂ = 50/25/25 discharge over 20 pulses. (a) Non-carbon containing species, (b) hydrocarbon species, and (c) oxygenated species.



Reaction (18) contributes 58% to C₃H₆ consumption, while reaction (19) contributes 41%.

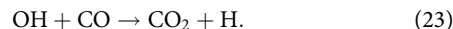
The long-lived oxygenated species formed in the plasma are shown in Fig. 3(c). The most abundant long-lived oxygenates are CO, CH₃OH, and CH₂O. CO is the most abundant after 20 pulses with a final density of $3.8 \times 10^{16} \text{ cm}^{-3}$. CO is primarily formed from H abstraction by O₂ from CHO (93%). As O₂ is a feedstock gas, this reaction is limited by the availability of CHO. The CO/H₂ ratio, relevant for syngas applications, reaches 4.3 at the end of 20 pulses. CH₃OH has a density of $2.1 \times 10^{16} \text{ cm}^{-3}$ after 20 pulses. CH₃OH is produced by H abstraction from CH₃O by CH₃O (53%) and O removal from CH₃O₂ (45%). The rates of these reactions are shown over the last pulse in Fig. 4(a). The peak rates occur at different times, attributed to when the densities of the reactants peak. The formation of CH₃O₂ occurs by CH₃ association with O₂, while CH₃OH requires CH₃O₂ to form. Therefore, the formation of CH₃OH from CH₃O occurs at a later time than the formation from CH₃O₂. CH₃OH is consumed in reactions with OH, shown in Fig. 4(b), though these reactions occur at 25% of the rate of CH₃OH formation.

CH₂O reaches a density of $1.4 \times 10^{16} \text{ cm}^{-3}$ after 20 pulses. CH₂O is produced through a variety of reactions. CH₂O is produced by H abstraction from CH₃O by CH₃O (32%), H abstraction from CH₃O (15%), and

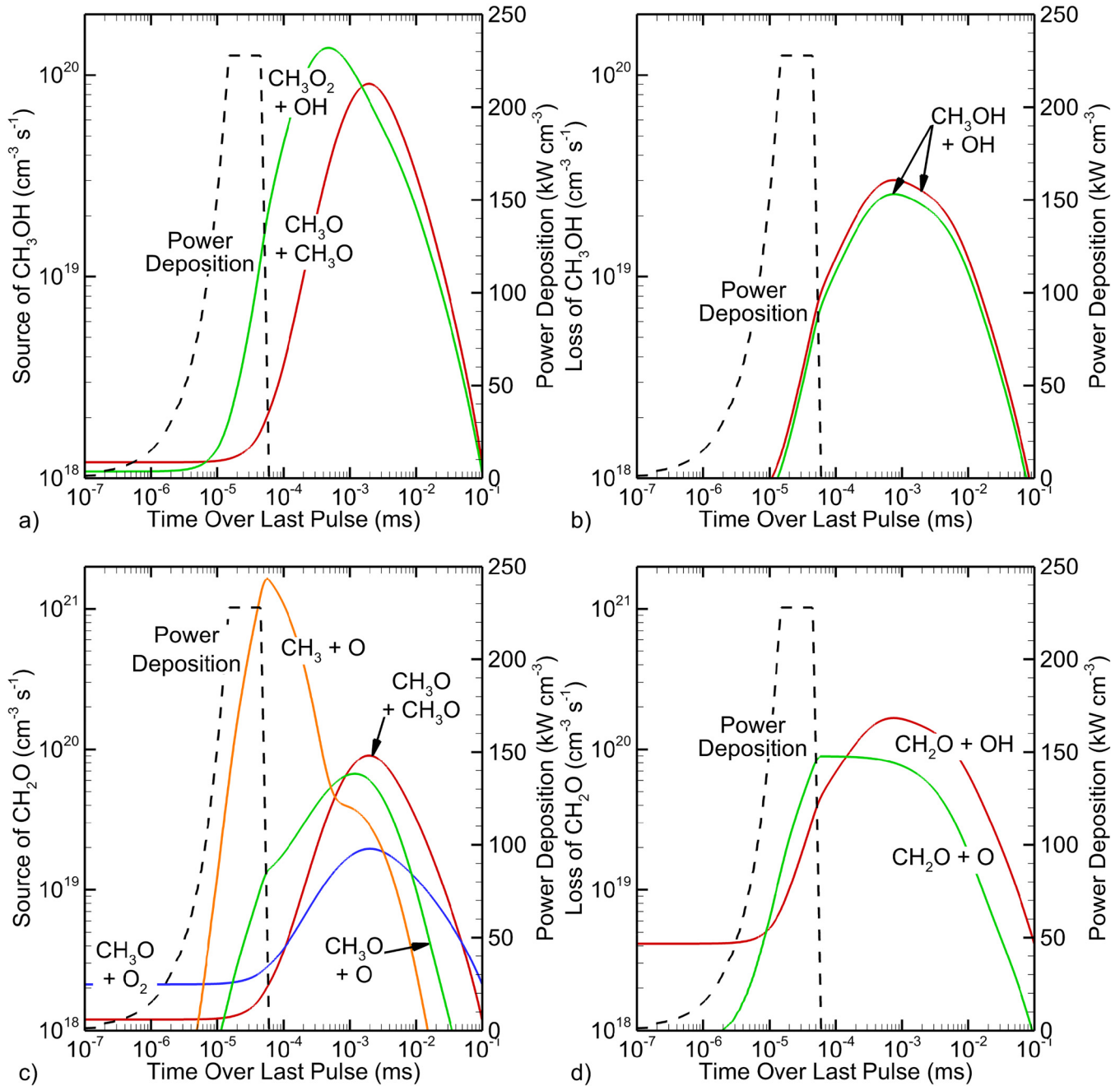


Reaction (20) contributes 13% to CH₂O formation and reaction (21) contributes 11%. As shown in Fig. 4(c), reaction (21) occurs during the discharge pulse, as both O and CH₃ are produced from the electron-impact dissociation of feedstock gases. The other three reactions that produce CH₂O rely on CH₃O, which reaches its maximum density 2 μs after the last pulse begins. As a result, the maximum rates of those reactions occur near 2 μs. While CH₂O is formed at an integrated rate of $5.6 \times 10^{16} \text{ cm}^{-3}$ over the 20 pulses, $4.0 \times 10^{16} \text{ cm}^{-3}$ of CH₂O is consumed over these 20 pulses. The main consumption mechanisms of CH₂O are CHO formation through H abstraction by OH (79%) and by O (18%), shown in Fig. 4(d). H abstraction by O reaches its maximum rate as the power begins to decrease, corresponding to the maximum in O density. OH, however, is formed later from the reactions of HO₂, and therefore, the rate peaks later at 0.7 μs.

While CO, CH₃OH, and CH₂O are the most abundant oxygenated species, significant densities of other oxygenated species are also formed. CO₂ is formed from



Reaction (22) contributes 33% of CO₂ formation and reaction (23) contributes 24%. CO₂ reaches a density of $2.3 \times 10^{15} \text{ cm}^{-3}$

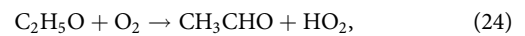


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FIG. 4. Rates of CH_3OH and CH_2O production and consumption in the $\text{Ar}/\text{CH}_4/\text{O}_2 = 50/25/25$ discharge over the last of 20 pulses. (a) CH_3OH production, (b) CH_3OH consumption, (c) CH_2O production, and (d) CH_2O consumption. Note that the consumption and production rates for each species are shown on the same scale.

after 20 pulses, an order of magnitude less than CO . However, as CO_2 is a greenhouse gas, its production is not desirable. CH_3OOH (methyl hydroperoxide) is formed by CH_3O_2 reacting with HO_2 (94%). $\text{C}_2\text{H}_5\text{OH}$ (ethanol) is also formed in the plasma. Similar to

CH_3OH , $\text{C}_2\text{H}_5\text{OH}$ is formed by the reactions between OH and $\text{C}_2\text{H}_5\text{O}_2$ (96%). CH_3CHO (acetaldehyde) is produced by



contributing 95% of CH_3CHO production. CH_3CHO is produced with an integrated rate of $2.3 \times 10^{15} \text{ cm}^{-3}$ while its consumption totals to $1.7 \times 10^{15} \text{ cm}^{-3}$. The dominant consumption mechanisms of CH_3CHO are H abstraction by OH (69%) and O (26%). The final oxygenated species shown in Fig. 3(c) is $\text{C}_2\text{H}_5\text{OOH}$ (ethyl hydroperoxide), produced by



contributing 91% to $\text{C}_2\text{H}_5\text{OOH}$ production. $\text{C}_2\text{H}_5\text{OOH}$ is produced with an integrated rate of $3.8 \times 10^{14} \text{ cm}^{-3}$ and consumed at $1.2 \times 10^{14} \text{ cm}^{-3}$ through H abstraction by OH (58%) and O (41%).

IV. GAS MIXTURES

A goal of this study is to determine the conditions that maximize the density of CH_3OH (and, to a lesser extent, CH_2O) while minimizing the amount of CO_2 formed. The gas mixture in which the plasma is sustained affects the fundamental plasma properties (electron density, T_e), as well as the long-lived species formed and their relative concentrations. In Sec. IV A, the fraction of Ar in the mixture is varied while holding the ratio CH_4/O_2 constant at 1/1. In Sec. IV B, the ratio of CH_4/O_2 is changed while keeping a constant 50% Ar mole fraction.

A. Ar dilution

Previous studies have shown that increasing the noble gas content in CH_4/CO_2 plasmas increases the conversion of CH_4 and CO_2 .^{18,19,21} In this section, the effect of changing the Ar percentage while keeping the CH_4/O_2 ratio constant at 1/1 as in the base case is examined.

As the Ar percentage increases from 0% to 95% Ar, the electron density when the power begins to decrease over the last pulse (45 ns) increases from 9.4×10^{12} to $7.9 \times 10^{13} \text{ cm}^{-3}$. With the increase in Ar, T_e increases from 2.98 to 3.27 eV. During the quasi-steady state, electron temperature is determined by the balance of ionization sources and charged particle losses. With the power profile being held constant, electron density is then determined by the power dissipation per electron at the self-sustaining electron temperature. The first inelastic electron-impact threshold with Ar is electronic excitation at an energy of 11.55 eV, while the ionization threshold is 16 eV. With Ar dilution, the mole-fraction weighted power dissipation per electron decreases as the rate of power dissipation by electrons with CH_4 or O_2 is larger due to their rotational-vibrational modes and lower threshold energies for electronic excitation and ionization. This condition is somewhat mediated at high power deposition when multistep ionization of argon begins to dominate, and at intermediate mole fractions of the molecular gas when Penning processes can be important.

The frequency of radical formation by electron-impact on a molecular species is $f_r = n_e \sum_i k_i(T_e)$, where the sum is over rate coefficients for radical formation. The total rate of radical formation by, for example, electron-impact on CH_4 is $f_i = n_e[\text{CH}_4] \sum_i k_i(T_e)$. With the increases in electron temperature and density with Ar dilution, f_r monotonically increases while

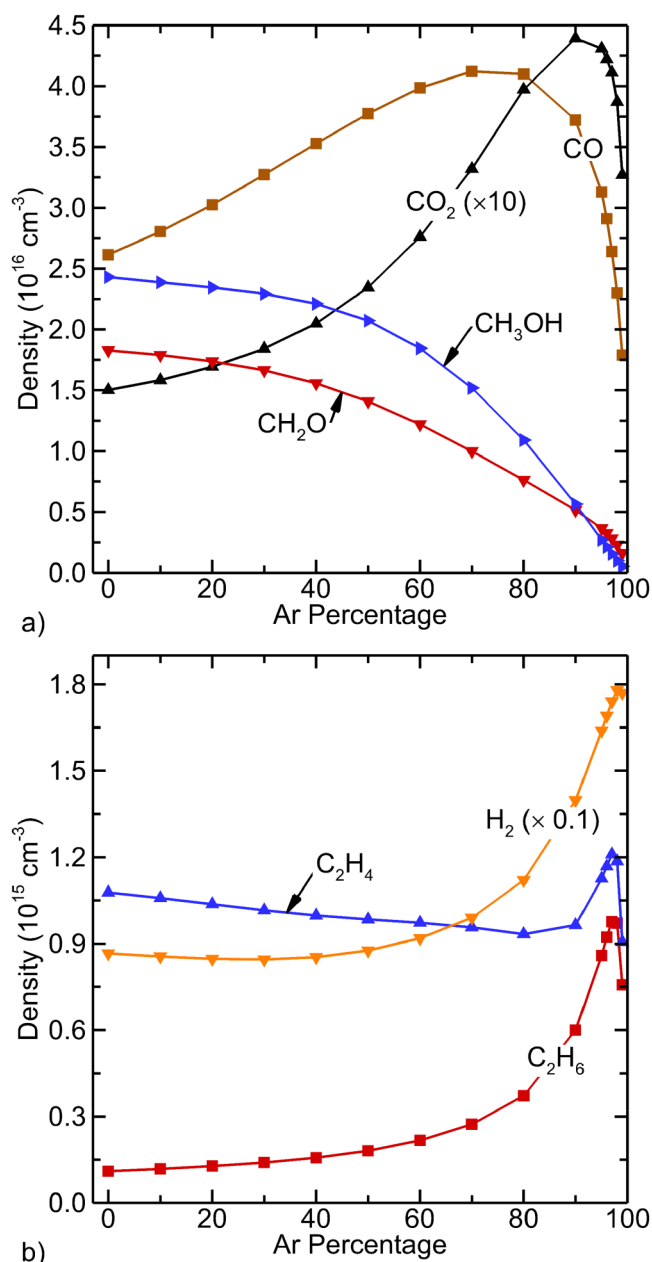


FIG. 5. Consequences of changing the Ar percentage in the gas mixture while keeping $\text{CH}_4/\text{O}_2 = 1/1$. (a) Long-lived oxygenates densities and (b) long-lived hydrocarbon species densities. Values are the maximum densities over the last of 20 pulses.

$[\text{CH}_4]$ monotonically decreases. These trends result in f_i being maximum at an intermediate Ar dilution.

The maximum oxygenated species densities (CH_3OH , CH_2O , CO , and CO_2) over the last pulse are shown in Fig. 5(a) as a

function of Ar percentage. CH_3OH and CH_2O both decrease as the Ar percentage increases. For CH_3OH , the decrease is slow below 40%, while above 40% Ar, the decrease becomes more rapid. While the production of CH_3OH due to CH_3O reacting with CH_3O and CH_3O_2 reacting with OH increases up to a 40% Ar mole fraction, the consumption of CH_3OH by OH also increases. The increase in the consumption of CH_3OH outweighs the increase in CH_3OH production, thereby decreasing its density.

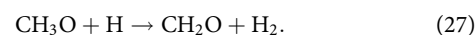
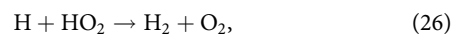
Above a mole fraction of 40% Ar, the consumption of CH_3OH by OH continues to increase while the production of CH_3OH decreases, leading to a more rapid decrease in the CH_3OH density. Similarly, CH_2O production relies on CH_3O and CH_3 , and increases through 40% Ar. However, the consumption of CH_2O due to OH also increases, thereby outweighing the increase in production to decrease the CH_2O density. Above 40% Ar, the density of CH_2O is not well correlated to the density of CH_3OH . While the production of CH_2O due to CH_3O reactions decreases above 40% Ar, its production due to CH_3 reacting with O increases. Therefore, the decrease in CH_2O production is less pronounced than in CH_3OH .

The production of both CH_3OH and CH_2O relies on the CH_3O radical. The production of CH_3O by CH_3O_2 reacting with O increases up to 40% Ar. CH_3O_2 production by association of CH_3 and O_2 also increases up to 40% Ar, following the production of CH_3 by H abstraction from CH_4 . CH_3O_2 and CH_3 production by H abstraction both increase with increasing T_{gas} , with T_{gas} reaching a maximum of 414 K in the afterglow at 40% and 50% Ar.

While the densities of CH_3OH and CH_2O decrease with increasing Ar, the densities of CO and CO_2 increase up to Ar mole fractions of 70%–90%, as shown in Fig. 5(a). CO reaches a maximum density of $4.1 \times 10^{16} \text{ cm}^{-3}$ at 70% Ar, while CO_2 reaches $4.4 \times 10^{15} \text{ cm}^{-3}$ at 90% Ar. CO relies on its production by H abstraction from CHO by O_2 , which increases to 70% Ar. CHO is formed by H abstraction from CH_2O by OH . Since CH_2O decreases as Ar increases, the increase in CHO production occurs because of the increase in T_{gas} as well as the increase in OH density. The density of OH increases up to 90% Ar as the production from HO_2 reacting with O increases. This trend prevails in spite of a decrease in OH production from HO_2 reacting with $\text{O}_2(^1\Delta)$. CO_2 production from CH_3CO reacting with O and OH reacting with CO increase to 80% Ar and 90% Ar, respectively. These reactions lead to a maximum CO_2 density at 90% Ar.

The long-lived hydrocarbon densities (C_2H_4 , C_2H_6 , and H_2) are shown in Fig. 5(b). The trends are different than the oxygenated species. The maximum in all the long-lived hydrocarbon densities occurs at 97%–98% Ar. These counter-intuitive trends result largely from the increase in electron density and rate coefficients for electron-impact processes, leading to the formation of long-lived hydrocarbons increasing more rapidly than the decrease in CH_4 density. H_2 remains relatively constant from 0% to 50% Ar and increases after 50% Ar. However, H_2 production from the electron-impact dissociation of CH_4 decreases as the mole fraction of Ar increases as there is less CH_4 in the discharge. Therefore, for the H_2 density to increase, the source of H_2 from other reactions must increase. H_2 production from other reactions, including CH_3 reacting with O , increases with the increasing Ar percentage. Other reactions contributing to H_2 production

that were not identified at 50% Ar become important after 70% Ar. These reactions include



The density of C_2H_4 exhibits a small decrease from 0% Ar to 80% Ar before increasing to 97% Ar. The production of C_2H_4 from CH reacting with CH_4 decreases with the increasing Ar percentage, but the production from C_2H_5^+ reacting with H_2O and from H abstraction from C_2H_5 increases. That increase offsets the decrease from CH reacting with CH_4 . For mole fractions larger than 80% Ar, the production from C_2H_5^+ reacting with H_2O and H abstraction from C_2H_5 further increases, driving an increase in C_2H_4 density. The density of C_2H_6 increases with increasing Ar mole fraction to 97%, though the increase becomes more rapid after 50% Ar. C_2H_6 is produced dominantly by the mutual association of CH_3 , and the maximum CH_3 density over the last pulse increases nearly linearly with the Ar percentage from $1.4 \times 10^{15} \text{ cm}^{-3}$ at 0% Ar to $1.8 \times 10^{13} \text{ cm}^{-3}$ at 95% Ar. After 97%–98% Ar, H_2 , C_2H_4 , and C_2H_6 densities decrease as CH_4 makes up less than 3% of the discharge—the increase in plasma density and electron temperature with increasing Ar mole fraction cannot compensate for the low mole fraction of CH_4 .

The fraction of the inlet O_2 remaining is between 70% and 80% for the change in Ar content shown in Fig. 5. On that basis alone, one might expect that the production of, for example, CH_3OH and CH_2O would decrease based on there being fewer O atoms available due to the depletion of the O_2 feedstock. However, the degree of dissociation of O_2 does not straightforwardly increase or decrease the production of CH_3OH and CH_2O . There should clearly be sufficient O atom production to enable the stoichiometry of the products. However, one of the eventual products of O_2 dissociation is OH which is involved in both the production and consumption reactions of CH_2O and CH_3OH . At some intermediate degree of O_2 dissociation, sufficient O atoms are produced while not also feeding the destruction pathways.

These results indicate that for the ratio of $\text{CH}_4/\text{O}_2 = 1/1$, operating with a small Ar mole fraction will maximize the CH_3OH and CH_2O densities while producing little CO_2 . In fact, at 95% Ar, the density of CO_2 is larger than the density of either CH_3OH or CH_2O . These trends are, however, sensitive to the ratio of CH_4/O_2 .

B. Ratio of CH_4 and O_2

Ultimately, the production of oxygenates depends on the reactions between carbon-containing and oxygen-containing species, while higher order hydrocarbon production depends largely on the reactions between non-oxygen containing species. In this regard, the branching to different oxygenated and hydrocarbon products likely depends on the ratio of CH_4 to O_2 in the mixture. In this section, these trends are discussed while the Ar mole fraction is held constant at 50%, and the CH_4 and O_2 percentages are varied. At low CH_4 percentages (high O_2 percentages), oxygenate formation is expected to dominate over hydrocarbon formation as oxygen is abundant. At high CH_4 percentages (low O_2

percentages), hydrocarbon formation is expected to dominate over oxygenate formation as oxygen is less abundant.

The electron density as the last power pulse begins to ramp down (45 ns) increases from $1.3 \times 10^{13} \text{ cm}^{-3}$ at 5% CH_4 to $3.4 \times 10^{13} \text{ cm}^{-3}$ at 45% CH_4 . This increase is due, in part, to decreased negative ion formation, with the maximum total negative ion density occurring at 20% CH_4 . The negative ions are dominantly the negative water cluster ions $\text{O}_2^-(\text{H}_2\text{O})$, $\text{O}_2^-(\text{H}_2\text{O})_2$, and $\text{O}^-(\text{H}_2\text{O})$ that follow the formation of O_2^- and O^- . While the maximum densities of O_2^- and O^- occur at 5% CH_4 (45% O_2), the maximum of the cluster ion densities occurs at 20% CH_4 as H_2O is formed in the discharge instead of being present as one of the feed-stock gases. While the electron density increases, T_e decreases from 3.21 eV at 5% CH_4 to 2.85 eV at 45% CH_4 .

The dominant long-lived species are shown in Fig. 6 with the oxygenates shown in Fig. 6(a) as a function of CH_4 and O_2 percentage. CH_3OH and CH_2O reach their maximum densities at 35% and 40% CH_4 , respectively. This is surprising because the O_2 content in the discharge is low (10%–15%). The production of both CH_3OH and CH_2O by CH_3O reacting with CH_3O increases to 35% CH_4 which explains the maximum CH_3OH density at 35% CH_4 . However, CH_2O reaches a maximum at 40% CH_4 due to its additional production from CH_3 reacting with O increasing to 40% CH_4 . Both CH_3OH and CH_2O production rely on CH_3O . The maximum CH_3O density occurs at 30% CH_4 , based largely on the production from CH_3O_2 which reaches a maximum at 25% CH_4 . The CH_3O_2 density is maximum at 30%–35% CH_4 . While the density of CH_3 reaches a maximum at 40% CH_4 , the association reaction to form CH_3O_2 depends on T_{gas} , which reaches its maximum at 25% CH_4 (414 K).

The fraction of inlet O_2 remaining is between 70% and 80% for the changing CH_4/O_2 content shown in Fig. 6 while the production of CH_3OH and CH_2O is maximum for an O_2 inlet flow of 10%–15%. The small amount of O_2 at this maximum in production may be counter-intuitive. The production of CH_3OH and CH_2O generally requires CH_3O as a precursor. CH_3O is produced from CH_3O_2 , which is generated by the reactions between $\text{CH}_3 + \text{O}_2$. The CH_3 content is critical for CH_3OH and CH_2O production and can be the rate-limiting step, provided, there is a critical amount of O_2 remaining.

The densities of CO and CO_2 follow a different trend than those of CH_3OH and CH_2O . These species are formed preferentially at low CH_4 percentages, with densities reaching a maximum at 20% CH_4 (30% O_2). The maximum in CO density follows the maximum of its production from H abstraction from CHO by O_2 . CHO is produced by H abstraction from CH_2O by either OH or O. The rates of these reactions increase to 20%–25% CH_4 due to the increase in both CH_2O density and T_{gas} . The production mechanisms of CO_2 (OH reacting with CO and CH_3CO reacting with O) reach their maximum at less than 25% CH_4 , leading to a maximum CO_2 density at 20% CH_4 .

The densities of long-lived hydrocarbons and H_2 are shown in Fig. 6(b). As expected, these species increase with increasing CH_4 , as they do not require oxygen to form. In fact, their production is enhanced since the hydrocarbon radicals which would otherwise be consumed by forming oxygenates are more readily available for hydrocarbon formation as the fraction of O_2 decreases. H_2 and C_2H_4 both reach their maximum density at 40% CH_4 . H_2 is

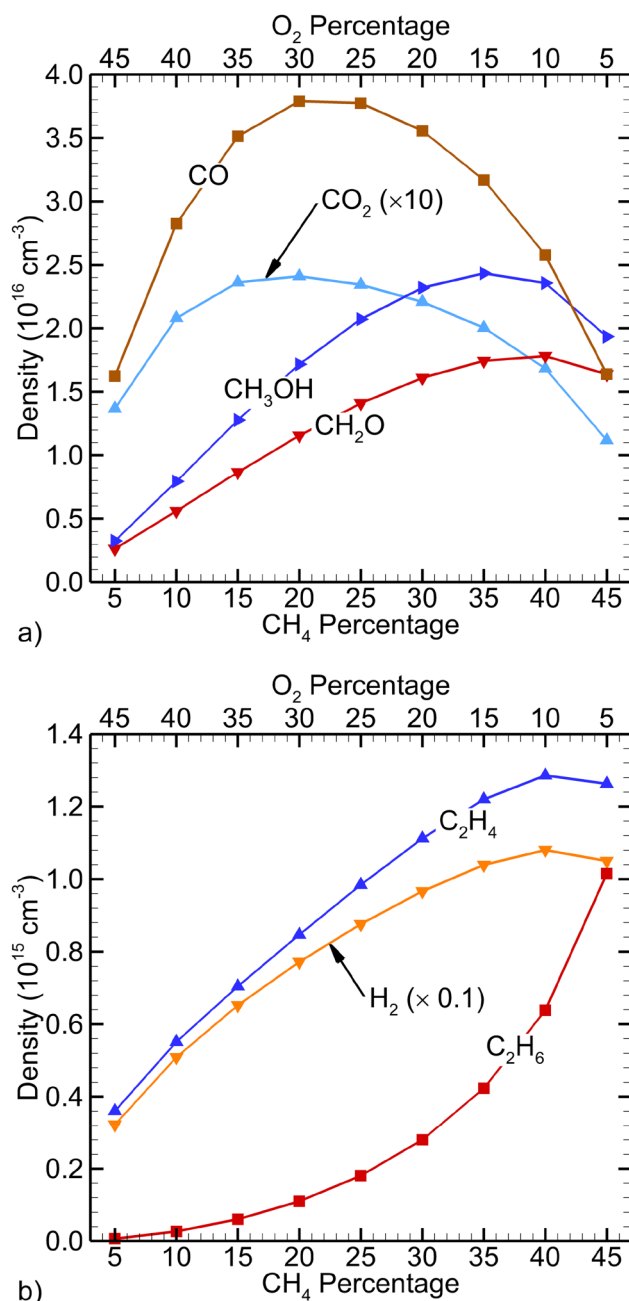


FIG. 6. Consequences of CH_4 and O_2 percentages while keeping a 50% Ar mole fraction. (a) Long-lived oxygenates densities and (b) long-lived hydrocarbon species densities. Values are the maximum over the last 20 pulses.

produced primarily from the electron-impact dissociation of CH_4 . While T_e decreases as the CH_4 percentage increases, the electron and CH_4 densities increase. These increases lead to an increase in the rate of electron-impact dissociation of CH_4 through 40% CH_4 .

The production of C_2H_4 by $C_2H_5^+$ reacting with H_2O decreases above 15% CH_4 , but the production by CH reacting with CH_4 increases. This increase occurs as the rate of electron-impact dissociation of CH_4 producing CH increases to 40% CH_4 . The density of C_2H_6 increases through 45% CH_4 which is primarily formed through mutual reactions of CH_3 . The integrated rate of mutual association of CH_3 increases from $8.4 \times 10^{12} \text{ cm}^{-3}$ at 5% CH_4 to $1.1 \times 10^{15} \text{ cm}^{-3}$ at 45% CH_4 .

Increasing the CH_4/O_2 ratio with a constant mole fraction of 50% Ar increases the production of CH_3OH and CH_2O and simultaneously decreases CO_2 . The results presented in this section show that at 50% Ar, 35%–40% CH_4 (10%–15% O_2) optimize CH_3OH and CH_2O production. At these conditions, the production of CO_2 decreases relative to its concentration at $CH_4/O_2 = 1/1$.

Although not a direct focus of this investigation, plasma conditions can be optimized to generate specific end products. For example, CH_3CHO (acetaldehyde) is widely used as an intermediate to generate acetic acid, peracetic acid, pyridine bases, and other chemicals. The production of CH_3CHO from ethylene³⁵ by the Wacker process is one of the most important processes in the chemical industry,³⁶ while acetaldehyde is itself a hazardous liquid. Less capital intensive and safer, point-of-use production of CH_3CHO would be advantageous for on-demand organic syntheses. For our setup, plasma generation of CH_3CHO is maximum for conditions similar to those of the other C_2 compounds. For 50% argon mixtures, CH_3CHO production is maximum with 40% CH_4 (10% O_2) resulting in a density of $8 \times 10^{14} \text{ cm}^{-3}$ after 20 pulses. For a ratio of $CH_4/O_2 = 1/1$, CH_3CHO production is maximum in the absence of argon, generating a density of $6 \times 10^{14} \text{ cm}^{-3}$ after 20 pulses.

V. CONVERSION AND ENERGY EXPENDITURE

The intent of this investigation was to address reaction mechanisms and not necessarily optimize conversion and energy efficiency for CH_4 oxygenation. Although global modeling is well suited to discussions of mechanisms, often, energy efficiencies are dependent on geometrical considerations that are difficult to include in global models—such as division in power deposition between sheaths and bulk, propagation of streamers or surface ionization waves, and gas flow (replenishment and pumping of gases).

That said, some assessments can be made. The conversion rates of CH_4 and O_2 were assessed for a sealed-off system to eliminate the uncertainties in accounting for gas flow and pressure stabilization while varying the CH_4/O_2 ratio with 50% Ar. The maximum CH_4 conversion was 2.2% at 5% CH_4 , decreasing to 0.7% for 45% CH_4 . The maximum O_2 conversion was 6.4% at 5% O_2 , decreasing to 3.0% for 45% O_2 . Xu and Tu measured CH_4 conversion in an AC DBD with pure CH_4 and reported a conversion percentage of 25.2% at the longest residence time (16 s).³⁷ Chen *et al.* reported a maximum conversion of 31.9% in a pure CH_4 nanosecond pulsed DBD.³⁸ Jo *et al.* reported a CH_4 conversion percentage of 7%–11% for Ar/ CH_4/O_2 plasmas in an AC DBD for varying O_2 and CH_4 concentrations.²² As these rates of conversion are dependent on residence time and energy deposition-per-molecule, direct comparisons are better made normalized by energy deposition.

The energy required for conversion (expressed as eV/molecule) was evaluated in a sealed-off system while varying the CH_4/O_2 ratios

at 50% Ar. For these conditions, the minimum energy cost for the conversion of CH_4 was 13.8 eV/molecule for Ar/ $CH_4/O_2 = 50/30/20$. Xu and Tu measured a maximum energy efficiency of 0.26 mmol/kJ (40 eV/molecule) for CH_4 conversion in an AC DBD operating in pure CH_4 .³⁷ While the calculated energy cost in this work was lower than that reported in Xu and Tu, the plasma in this work was formed in Ar/ CH_4/O_2 instead of pure CH_4 . The calculated energy cost for the production of CH_3OH was minimum at Ar/ $CH_4/O_2 = 50/35/15$ at 46.6 eV/molecule. Wang *et al.* reported a maximum energy efficiency of CH_3OH production of 0.83 mol/kWh (45 eV/molecule) in an AC DBD operating in CH_4/CO_2 ,²³ comparable to the calculated energy cost in this work.

VI. CONCLUDING REMARKS

The formation of value-added chemicals in atmospheric pressure plasmas can provide an alternative to energy-intensive steam and dry reforming of CH_4 . The production of oxygenates, including CH_3OH and CH_2O , using plasmas sustained in Ar/ CH_4/O_2 was investigated using a 0D plasma chemistry model *GlobalKin*. The geometry was focused on narrow channels as might be used in microfluidic devices where a scale is achieved by massively parallel sets of microchannels. The goal of this study was to investigate reaction mechanisms resulting in the production of CH_3OH and CH_2O while minimizing the production of the greenhouse gas CO_2 .

First, the plasma chemistry in Ar/ $CH_4/O_2 = 50/25/25$ was examined. Of the many radical species that are formed in the plasma, CH_3 and O are formed directly by the electron-impact dissociation of CH_4 and O_2 . Others, particularly the oxygenated radicals CH_3O_2 , CH_3O , and CHO, depend on those initial radicals for their formation. Further reaction of these species branch to several products. The oxygenates, including CO, CH_3OH , and CH_2O , comprise most of the carbon-containing products while the greenhouse gas CO_2 is also formed. Pure hydrocarbon products (C_2H_4 and C_2H_6) are also formed, albeit at an order of magnitude of lower density. The formation of CH_3OH relies on CH_3O and CH_3O_2 , while the formation of CH_2O relies on CH_3O and CH_3 . CO is formed almost exclusively by H abstraction from CHO.

The mole fractions of the feed gas affect the selectivity of the process and, in particular, the production of CH_3OH , CH_2O , and CO_2 . First, the consequences of Ar percentage were examined while keeping the ratio $CH_4/O_2 = 1/1$. CH_3OH and CH_2O have maximum densities at 0% Ar, while the density of CO is the highest at 70% Ar and CO_2 is the highest at 90% Ar. If the goal is, for example, CO production for syngas, moderate Ar additions are beneficial. However, if the goal is CH_3OH or CH_2O , Ar dilution is not beneficial. When varying the CH_4/O_2 ratio at a constant 50% Ar, the densities of CH_3OH and CH_2O are maximum at 35%–40% CH_4 (10%–15% O_2) while the densities of CO and CO_2 are the maximum at 20% CH_4 . Therefore, a CH_4 rich discharge of 35%–40% favors CH_3OH and CH_2O production while minimizing CO_2 formation.

Conventional microfluidic labs-on-a-chip are intentionally designed to have long residence times (many to tens of seconds or more), a goal achieved with channel lengths of up to several meters. Although optimum for microfluidic processing, this is not necessarily the geometry that would be implemented for plasma conversion using microchannels. With these long channel lengths

and residence times, the desired products would also be subject to lengthy electron-impact dissociation and ionization. An advantage of plasma conversion using microchannels is that the precise time of plasma exposure can be set by the length of the channel and gas flow. Although not the focus of this investigation, we anticipate that optimized plasma conversion using microchannels would consist of large arrays of parallel channels, with residence time in any given channel being tens to hundreds of ms. These parameters would be chosen to optimize the conversion of the feedstock gas while not detrimentally undergoing plasma dissociation of the desired products.

SUPPLEMENTARY MATERIAL

See the [supplementary material](#) for additions and revisions to the prior published reaction mechanism³³ for plasmas sustained in Ar/CH₄ mixtures to account for the addition of oxygen.

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AUTHOR DECLARATIONS

Conflict of Interest

The authors have no conflicts of interest.

Author Contributions

Mackenzie Meyer: Conceptualization (lead); Data curation (lead); Formal analysis (lead); Investigation (lead); Methodology (equal); Writing – original draft (lead); Writing – review & editing (equal). **Ryan Hartman:** Funding acquisition (equal); Project administration (equal); Supervision (equal); Writing – review & editing (equal). **Mark J. Kushner:** Formal analysis (supporting); Funding acquisition (equal); Investigation (supporting); Methodology (equal); Project administration (equal); Resources (equal); Supervision (equal); Writing – review & editing (equal).

DATA AVAILABILITY

The data that support the findings of this study are available from the corresponding author upon reasonable request.

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